

Power Supply IC Series for TFT-LCD Panels

# Gamma voltage generated IC with built-in DAC

#### **General Description**

The feature of gamma voltage generated IC BD81026MUV provides a single-chip solution with a high-precision 10-bit DAC setting controlled by  $I^2$ C serial communications interface and a buffer amp (12ch).

#### Features

- Built in 10bit DAC (12ch)
- Built in DAC Output Buffer Amplifier (12ch)
- Double Register Switch Synchronously Function (BKSEL)
- DAC Output Latch Function (LD)
- I<sup>2</sup>C Interface (SDA, SCL) STANDARD-MODE, FAST-MODE changeable
- Thermal Shut-Down Circuit
- Under Voltage Lock-Out Function
- Power ON Reset Circuit
- Input Tolerant (SDA, SCL, BKSEL, LD)

#### Applications

It may be used with TFT-LCD panels, such as big screen and high resolution LCD televisions.

#### **Key Specifications**

- Power Supply Voltage Range(VDD): 2.1V to 3.6V
- Power Supply Voltage Range(VCC): 8.0V to 18.0V
- Operating Temperature Range: -25°C to +85°C

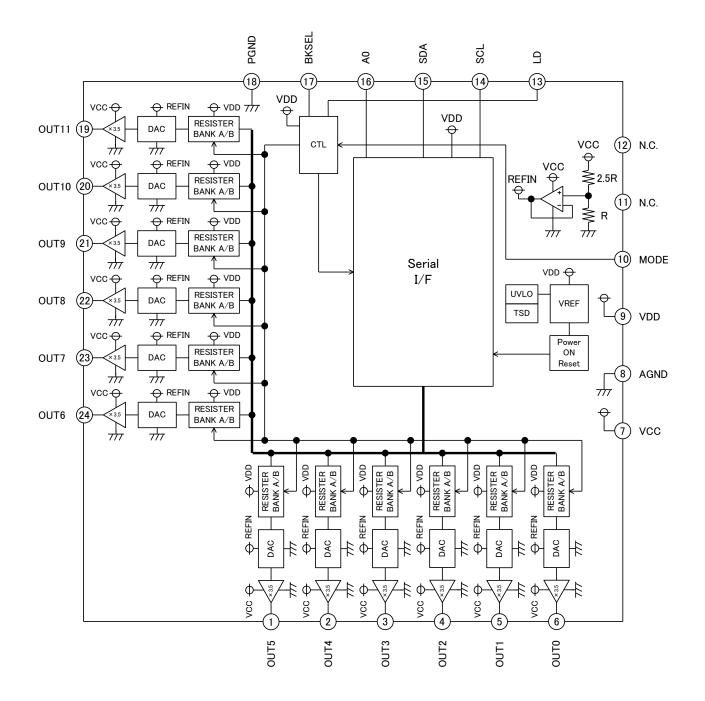
#### Package

W(Typ) x D(Typ) x H(Max)

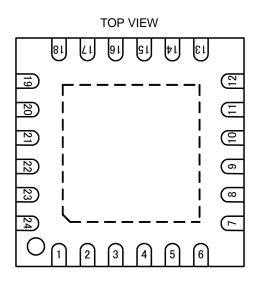


OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

## **Block Diagram**



## **Pin Configuration**



#### **Pin Description**

PIN No.	Pin name	Function	PIN No.	Pin name	Function
1	OUT5	Gamma output pin 5	13	LD	Latch pin (Note 1)
2	OUT4	Gamma output pin 4	14	SCL	Serial clock input pin
3	OUT3	Gamma output pin 3	15	SDA	Serial data input pin
4	OUT2	Gamma output pin 2	16	A0	Device address switching pin
					BANK select pin (Note 2)
5	OUT1 G	Gamma output pin 1	17	BKSEL	L : BANK A select
					H : BANK B select
6	OUT0	Gamma output pin 0	18	PGND	DAC output buffer amplifier GND input
7	VCC	Buffer amplifier power supply input for DAC output	19	OUT11	Gamma output pin 11
8	AGND	Logic, Analog GND input	20	OUT10	Gamma output pin 10
9	VDD	Logic, Analog power supply input	21	OUT9	Gamma output pin 9
10	MODE	BKSEL/LD mode switching pin L : BKSEL writing mode select H : LD writing mode select	22	OUT8	Gamma output pin 8
11	N.C.	-	23	OUT7	Gamma output pin 7
12	N.C.	-	24	OUT6	Gamma output pin 6

(Note 1) When Data writing function by LD pin control is not used, please connect LD pin to GND. (Note 2) When Data writing function by BKSEL pin control is not used, please connect BKSEL pin to GND.

## Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage 1	V <sub>DD</sub>	4.5	V
Power Supply Voltage 2	Vcc	19.0	V
Functional Pin Voltage	Vbksel, Va0, Vld Vmode	4.5	V
2 Lines Serial Pin Voltage	Vsda, Vscl	4.5	V
Junction Temperature	Tjmax	150	°C
Power Dissipation	Pd	3.56 (Note 1)	W
Operating Temperature Range	Topr	-25 to +85	°C
Storage Temperature Range	Tstg	-55 to +150	°C

 (Note 1) To use the IC at temperatures over Ta=25°C, derate power rating by 28.5mW/°C. When mounted on a four-layer glass epoxy board measuring 74.2mm x 74.2mm x 1.6mm (All layer with copper foil: 5505mm<sup>2</sup>).
 Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

#### Recommended Operating Conditions (Ta=-25°C to +85°C)

Parameter	Symbol	Min	Max	Unit
Power Supply Voltage 1	V <sub>DD</sub>	2.1	3.6	V
Power Supply Voltage 2	Vcc	8.0	18.0	V
Function Pin Voltage	Vbksel, Vao, Vld Vmode	-0.1	+3.6	V
2 Lines Serial Pin Voltage	Vsda, Vscl	-0.1	+3.6	V
2 Lines Serial Frequency	fc∟к	-	400	kHz

## **BD81026MUV**

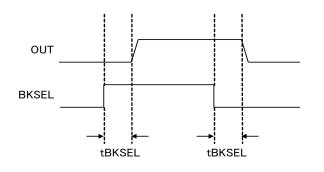
## **Electrical Characteristics** (Unless otherwise specified, Ta=25°C, V<sub>DD</sub>=3.3V, V<sub>CC</sub>=12.6V)

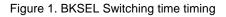
Deremeter	Sumbol	•	Limit		Linit	Condition
Parameter	Symbol	MIN	TYP	MAX	Unit	Condition
【 Gamma Amplifier 】					1	
Sink Current Capability Nch Side (AMP0)	looA	-	-	-10	mA	During REG0=3AFh (11.6V ) setting, V <sub>OUT0</sub> =12.6V input
Sink Current Capability Nch Side (AMP1 to AMP5, AMP7 to AMP10)	looB	-	-	-30	mA	During REG1 to REG5, REG7 to REG10=1E8h (6.0V) setting, Vout1 to Vout5, Vout7 to Vout10=7V
Sink Current Capability Nch Side (AMP6)	looC	-	-	-60	mA	During REG6=1E8h (6.0V) setting, V <sub>OUT6</sub> =7V
Sink Current Capability Nch Side (AMP11)	looD		-	-60	mA	During REG11=051h (1.0V) setting, V <sub>OUT11</sub> =2V input
Source Current Capability Pch Side (AMP0)	IoiA	60	-	-	mA	During REG0=3AFh (11.6V) setting, Vouto=10.6V input
Source Current Capability Pch Side (AMP1 to AMP5, AMP7 to AMP10)	loiB	30	-	-	mA	During REG1 to REG5, REG7 to REG10=1E8h (6.0V) setting, V <sub>OUT1</sub> to V <sub>OUT5</sub> , V <sub>OUT7</sub> to V <sub>OUT10</sub> =5V
Source Current Capability Pch Side (AMP6)	loiC	60	-	-	mA	During REG6=1E8h (6.0V) setting, V <sub>OUT6</sub> =5V
Source Current Capability Pch Side (AMP11)	loiD	10	-	-	mA	During REG11=051h (1.0V) setting, V <sub>OUT11</sub> =0V input
Load Stability (OUT0)	⊿vo-a	-	10	70	mV	During REG0=1E8h (6.0V) setting, Io=0mA to -30mA
Load Stability (OUT1 to OUT5, OUT7 to OUT10)	⊿vo-в	-	10	70	mV	During REG1 to REG5, REG7 to REG10=1E8h (6.0V) setting, Io=-15mA to +15mA
Load Stability (OUT6)	⊿vo-c	-	10	70	mV	During REG6=1E8h (6.0V) setting, Io=-15mA to +15mA
Load Stability (OUT11)	⊿vo-d	-	10	70	mV	During REG11=1E8h (6.0V) setting, Io=0mA to +30mA
MAX Output Voltage (OUT0)	VOH-A	Vcc-0.2	Vcc-0.1	-	V	Io=-30mA
MAX Output Voltage (OUT1 to OUT5, OUT7 to OUT10)	VOH-B	Vcc-1.0	Vcc-0.6	-	V	lo=-15mA
MAX Output Voltage (OUT6)	VOH-C	Vcc-1.0	Vcc-0.6	-	V	Io=-15mA
MAX Output Voltage (OUT11)	VOH-D	V <sub>cc</sub> -1.2	V <sub>cc</sub> -0.75	-	V	I <sub>O</sub> =-15mA
MIN Output Voltage (OUT0)	VOL-A	-	0.75	1.20	V	I <sub>0</sub> =+15mA
MIN Output Voltage (OUT1 to OUT5, OUT7 to OUT10)	VOL-B	-	0.6	1.0	V	Io=+15mA
MIN Output Voltage (OUT6)	VOL-C	-	0.6	1.0	V	I <sub>0</sub> =+15mA
MIN Output Voltage (OUT11)	VOL-D	-	0.1	0.2	V	I <sub>0</sub> =+30mA
Slew Rate (AMP0)	SR-A	1	4	-	V/µsec	OUT0=No load
Slew Rate (AMP1 to AMP5, AMP7 to AMP10)	SR-B	1	4	-	V/µsec	OUT1 to OUT5,OUT7 to OUT10=No load
Slew Rate (AMP6)	SR-C	1	4	-	V/µsec	OUT6=No load
Slew Rate (AMP11)	SR-D	1	4	-	V/µsec	OUT11=No load

#### Electrical Characteristics – Continued (Unless otherwise specified, Ta=25°C, V<sub>DD</sub>=3.3V, V<sub>CC</sub>=12.6V)

	<b>•</b> • •	Limit					
Parameter	Symbol	MIN	TYP	MAX	Unit	Condition	
【 10 Bit DAC 】							
Resolution	RES	-	10	-	Bit		
Integral Non-Linearity Error (INL)	LE	-2	-	+2	LSB	005h to 3FAh is the allowable margin of error against the ideal linear.	
Differential Non-Linearity Error (DNL)	DLE	-2	-	+2	LSB	005h to 3FAh is the allowable margin of error against the ideal increase of 1LSB.	
Output Voltage Precision	Vo	5.945	6.005	6.065	V	During REG0 to REG11=1E8h (6.0V) setting	
Output Voltage Thermal Characteristics	Vτ	-50	-	+50	mV	During REG0 to REG11=1E8h (6.0V) setting, Ta=-25°C to +85°C	
Control Signal 1 (BKSEL, A	40, LD, MO	DE)					
Threshold Voltage 1	$V_{th1A}$	0.8	-	1.7	V	V <sub>DD</sub> =3.3V	
Threshold Voltage 2	V <sub>th1B</sub>	0.6	-	1.7	V	V <sub>DD</sub> =2.5V	
Pull-down Resistor	R <sub>ctl</sub>	21	30	39	kΩ		
Control Signal 2 (SDA, SC	L) ]						
Threshold Voltage 1	V <sub>th2A</sub>	0.8	-	1.7	V	V <sub>DD</sub> =3.3V	
Threshold Voltage 2	V <sub>th2B</sub>	0.6	-	1.7	V	V <sub>DD</sub> =2.5V	
Minimum Output Voltage	V <sub>OCL</sub>	-	-	0.4	V	I <sub>SDA</sub> =3mA	
[ Whole Device ]	1				1		
VDD Power ON Reset Start-up Voltage	V <sub>det1</sub>	1.75	1.9	2.05	V	VDD Rising voltage	
VDD Under Voltage Lock-Out Voltage	Vdduv	1.55	1.7	1.85	V	VDD Falling voltage	
VDD Under Voltage Lock-Out Hysteresis Voltage	Vddhy	-	200	-	mV		
VCC Under Voltage Lock-Out Release Voltage	V <sub>det2</sub>	3.2	3.4	3.6	V	VCC Rising voltage	
VCC Under Voltage Lock-Out Voltage	Vccuv	2.8	3.0	3.2	V	VCC Falling voltage	
VCC Under Voltage Lock-Out Hysteresis Voltage	Vcchy	-	400	-	mV		
BKSEL Switching Time (Note 1)	<b>t</b> BKSEL	-	0.3	1.0	µsec		
_D Switching Time (Note 2)	t <sub>LD</sub>	-	0.3	1.0	µsec		
/DD Circuit Current	lcc∟	0.16	0.25	0.34	mA	Output No-load , DAC initial value setting	
VCC Circuit Current	Іссн	2	4	6	mA	Output No-load , DAC initial value setting	

(Note 1) BKSEL switching time timing is shown below.





(Note 2) LD switching time timing is shown below.

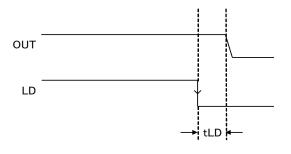


Figure 2. LD Switching time timing

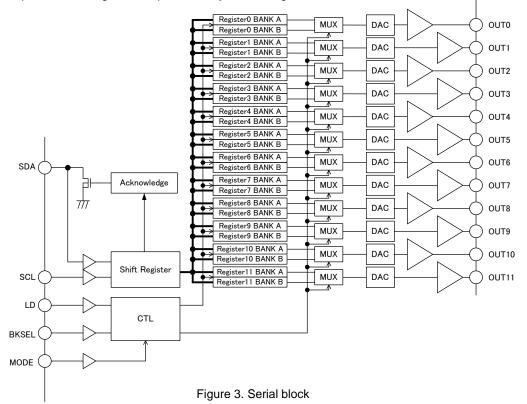
## Operation of each block

(1) 10 Bit DAC block

#### Serial data control block

The serial interface uses a 2-line serial data format (SCL, SDA).

The serial data control block consists of a register that stores data from the SDA and SCL pins, and a DAC circuit that receives the output from this register and provides adjusted voltages to other IC blocks.



· Register ( Ch0 to Ch11 )

A serial signal (consisting of 10-bit gamma correction voltage values) input using the serial interface or I<sup>2</sup>C bus interface is held for each register address.

Data is initialized by the reset signal generated during a power-on reset.

Register is selectable by BKSEL pin. (For detail, refer to P.9.)

Also, it is selectable that either revises the DAC output setting voltage by LD pin to the data, read to register. (For detail, refer to P.10.)

Data writing mode selector

Switching MODE pin High/Low enables changing data switching mode. During MODE=Low, a data is rewrote by Double Register switching function of BKSEL control. During MODE=High, a data is rewrote by DAC output latch function of LD control. MODE pin is pulled down inside so that at open state, it is Low. If it is set to High, connect to VDD.

• DAC

The DAC LOGIC converts the 10-bit digital signal read to the register to a voltage.

• AMP (Ch0 to Ch11)

The Amp amplifies the voltage output from the DAC LOGIC.

While Under Voltage Lock-Out (UVLO) circuit or Thermal Shut Down (TSD) circuit is operating, output goes into Hi-z. In case connecting high capacity capacitor with low ESR, damping is needed with a resistor to keep phase margin.

## ■Output Voltage setting mode

Writes to a register address specified by I<sup>2</sup>C BUS.

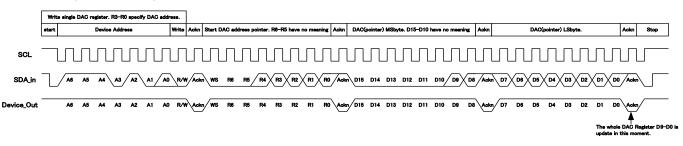
Mode for writing from I<sup>2</sup>C BUS to register are ( i )Single mode and ( ii )Multi mode.

On single mode, write data to one designated register.

On multi mode, multi data write can be performed continuously from a start address register specified with the second byte of data.

Single mode or multi mode can be configured by having or not having "stop bit".

#### (i) Single mode timing chart



#### Figure 4. Output voltage setting (Single mode)

#### (ii) Multi mode timing chart

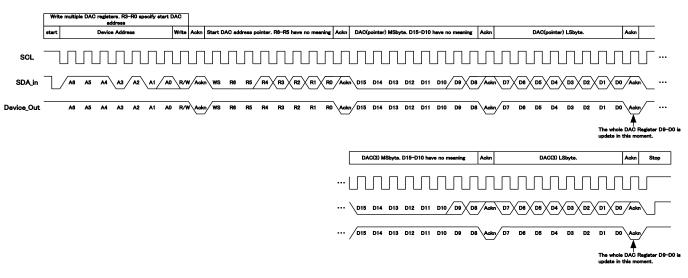


Figure 5. Output voltage setting (Multi mode)

#### Device address

Device address A6 to A1 are specific to the IC and should be set as follows: (A6 to A0) =111010(A0). A0 can be set by external. It is pulled-up inside so that in open state, it turns to"0". If setting to "1", connect to VDD.

#### Command interface

Use I<sup>2</sup>C BUS for command interface with host. Writing or reading by specifying 1 byte select address, along with slave address. I<sup>2</sup>C BUS Slave mode format is shown below.

		MSB		LSB		MSB	LSB		MSB	LSB			
	S	Sla	ave Addre	ess	А	Select A	ddress	Α	DA	TA	А	Р	
S			: :	START	conditi	ion							
S	lave Ac	ddress		After sla <sup>.</sup> (L). (M		dress (7bit), s st)	end total 8t	oit data	with either F	READ mode	e (H) o	r WRIT	E mode
Α			: .	Acknowl	edge								
				Added	ackno	wledge bit pe	er byte in se	nding	and receiving	g data.			
						sent/ receive eceiving "H"				ived.			
s	elect A	ddress			•	ect address.		UI ack	nowieuge.				
-	ATA	aarooo				nding/ Receiv	ing data.	(MSB	first)				
Р				STOP co		•	0						
-						(Oin alla an a	1-)						
I		e where S	Slave Ad		A	(Single mod		Pagiot		A Regis	tor1 D	ΔΤΔ1	A P
		3 (X.)	E8h or		A	01h	ess A	Regis	ter1 DATA0 03h	A Regis	<mark>ster1 D</mark> FCh		
	(∟					UIII			0011		1 011		
							: Slave from	n maste	er	: Mast	er fron	n slave	
т	he case	e where	e writing 3	3FCh fro	m DA	C0 to DAC3 (	Multi mode	)					
	S	Slave	Address	A	Select Address	A Regis	A	egister0 DATA1	A Registe	A	_	er1 to 3 ),DATA1	AP
	(E	X.)E8h	or EAh		00h	03	h	FCh	03h				
							: Slave from	n maste	er	: Mast	er fron	n slave	

■ Double Register switching function

When setting Low of MODE pin, it is able to switch BANK A or BANK B by changing High/Low of BKSEL pin. During BKSEL=Low, connect BANK A to DAC.

During BKSEL=High, connect BANK B to DAC.

- DAC output switching function by LD pin During MODE pin = High setting, depending on LD pin condition, DAC output is able to switch.
- In case LD=Low, write a data to a register of a specified address and DAC output outputs the data written to the register.
   (Defects Figure 6: DAC output outputs and the print (i))

(Refer to Figure 6: DAC output switching operation by LD pin (i).)

• In case LD=High, write a data to a register of a specified address and DAC output maintains the previous data setting. In this condition, if LD pin switches from High to Low, all DAC output (OUT0 to OUT11) outputs synchronously a data, written to a register.

(Refer to Figure 6: DAC output switching operation by LD pin (ii).)

(i) When LE	) = Low, DAC output switching operation
LD _	
SDA –	etart Device Address & Register Address & DAC(0) MLByte & DAC(0) LSByte & DAC(1) MLByte & DAC(1) LSByte & DAC(11) MLByte & DAC(11) MLByte & DAC(11) LSByte & STOP
DAC OUT0 _	Outputs a writton data  U Outputs a writton data
DAC OUT1 _	
E DAC OUT11	Cutpute a written data

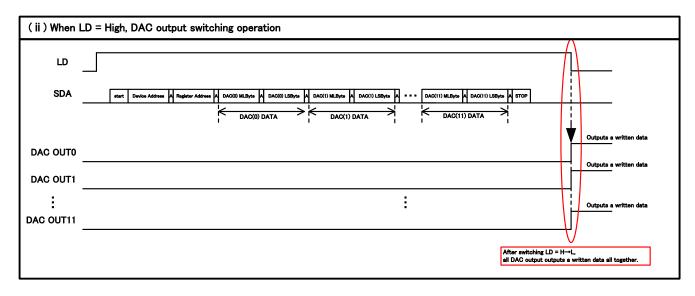


Figure 6. DAC output switching operation by LD pin

#### Register address

BANK A and BANK B register addresses are configured by the chart below.

Register name			BANK A	1		Initial	Initial Register name		BANK B					
Register name	R4	R3	R2	R1	R0	Value	Register name	R4	R3	R2	R1	R0	Value	
Register 0 BANK A	0	0	0	0	0	000h	Register 0 BANK B	1	0	0	0	0	000h	
Register 1 BANK A	0	0	0	0	1	000h	Register 1 BANK B	1	0	0	0	1	000h	
Register 2 BANK A	0	0	0	1	0	000h	Register 2 BANK B	1	0	0	1	0	000h	
Register 3 BANK A	0	0	0	1	1	000h	Register 3 BANK B	1	0	0	1	1	000h	
Register 4 BANK A	0	0	1	0	0	000h	Register 4 BANK B	1	0	1	0	0	000h	
Register 5 BANK A	0	0	1	0	1	000h	Register 5 BANK B	1	0	1	0	1	000h	
Register 6 BANK A	0	0	1	1	0	000h	Register 6 BANK B	1	0	1	1	0	000h	
Register 7 BANK A	0	0	1	1	1	000h	Register 7 BANK B	1	0	1	1	1	000h	
Register 8 BANK A	0	1	0	0	0	000h	Register 8 BANK B	1	1	0	0	0	000h	
Register 9 BANK A	0	1	0	0	1	000h	Register 9 BANK B	1	1	0	0	1	000h	
Register 10 BANK A	0	1	0	1	0	000h	Register 10 BANK B	1	1	0	1	0	000h	
Register 11 BANK A	0	1	0	1	1	000h	Register 11 BANK B	1	1	0	1	1	000h	

For Register address, lower 5bit (R4 to R0) at 2<sup>nd</sup> byte will be used. R6 to R5 is "Don't Care."

#### (2) Power On Reset

At VDD input, it generates Reset signal and initialize serial I/F and each register.

#### (3) UVLO (Under Voltage Lock Out)

When VDD and VCC falls under the setting value, Under Voltage Lock Out function is activated and output will be Hi-Z. If VDD UVLO is operated, initialize a register.

If VCC UVLO is operated, NOT initialize a register.

#### (4) TSD(Thermal Shut Down)

The TSD circuit turns output Hi-z when the chip temperature reaches or exceeds approximately

175°C in order to prevent thermal destruction or thermal runaway. When the chip returns to a specified temperature, the circuit resets.

The TSD circuit is designed only to protect the IC itself. Application thermal design should ensure operation of the IC below the junction temperature of approximately 150°C.

#### Power supply sequence

Activate VDD before VCC to avoid a malfunction due to undefined logic in LOGIC circuit. Inputs serial data after canceling Power on Reset.

In case power supply turns OFF, it is recommended after VCC OFF, VDD OFF ,or VCC and VDD OFF synchronously. If VDD turns OFF before VCC OFF, output condition may not be stable because of LOGIC circuit instability. Please demonstrate and test fully on an application board.

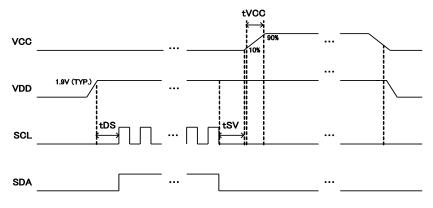


Figure 7. Power supply sequence

#### Power supply sequence typical value

Deveryeter	Current al		Limit		1.1	Condition	
Parameter	Symbol	Min	Тур	Max	Unit		
Serial Input Timing	tos	100	-	-	μs		
VCC Input Timing	t <sub>SV</sub>	10	-	-	μs		
VCC Rising Time	tvcc	1	-	-	ms		

## I<sup>2</sup>C Timing

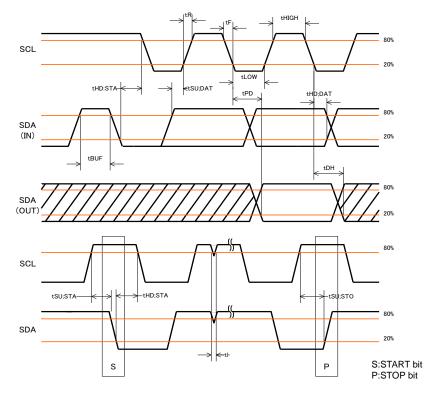


Figure 8. I<sup>2</sup>C timing

#### •Timing rule

	SYMBOL	N	ORMAL mo	de		Linit		
PARAMETER	STINBUL	MIN	TYP	MAX	MIN	TYP	MAX	Unit
SCL frequency	fscl	-	-	100	-	-	400	kHz
SCL"H" time	tнigн	4.0	-	-	0.6	-	-	μs
SCL"L" time	t <sub>LOW</sub>	4.7	-	-	1.2	-	-	μs
Rising time	t <sub>R</sub>	-	-	1.0	-	-	0.3	μs
Falling time	t⊧	-	-	0.3	-	-	0.3	μs
Start condition holding time	t <sub>HD;STA</sub>	4.0	-	-	0.6	-	-	μs
Start condition set-up time	t <sub>su;sta</sub>	4.7	-	-	0.6	-	-	μs
SDA holding time	thd; dat	200	-	-	100	-	-	ns
SDA set-up time	tsu;dat	200	-	-	100	-	-	ns
Acknowledge delay time	t <sub>PD</sub>	-	-	0.9	-	-	0.9	μs
Acknowledge hold time	t <sub>DH</sub>	-	0.1	-	-	0.1	-	μs
Stop condition set-up time	tsu;sto	4.7	-	-	0.6	-	-	μs
BUS open time	<b>t</b> BUF	4.7	-	-	1.2	-	-	μs
Noise spike width	tı	-	0.1	-	-	0.1	-	μs

#### Gamma output setting

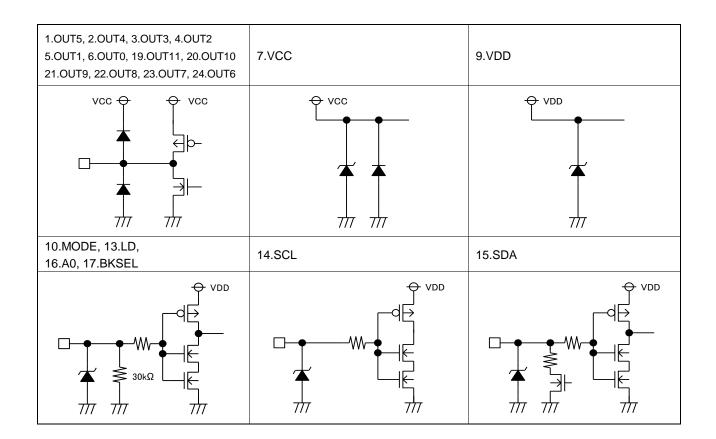
Relation between gamma output voltage (OUT0 to OUT11) and DAC setting value is shown as below.

 $Output \ voltage \ (OUT0 \ to \ OUT11) = \frac{DAC \ setting \ value}{1024} \times VCC$ 

DAC setting value range is 0 to 1023.

Gamma output OUT0 to OUT11 is outputted after VCC UVLO release. During UVLO detection, output is Hi-Z.

## I/O Equivalent circuits



## **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

## **Operational Notes – continued**

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

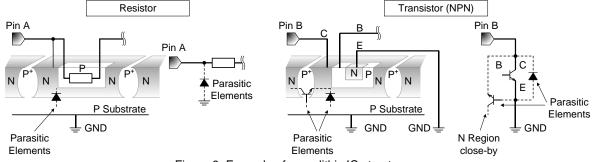


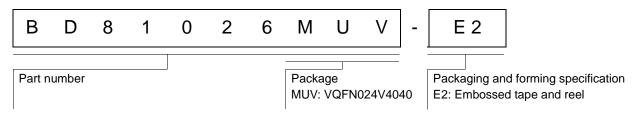
Figure 9. Example of monolithic IC structure

#### 13. Thermal Shutdown Circuit(TSD)

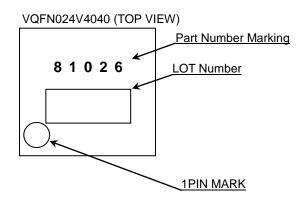
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

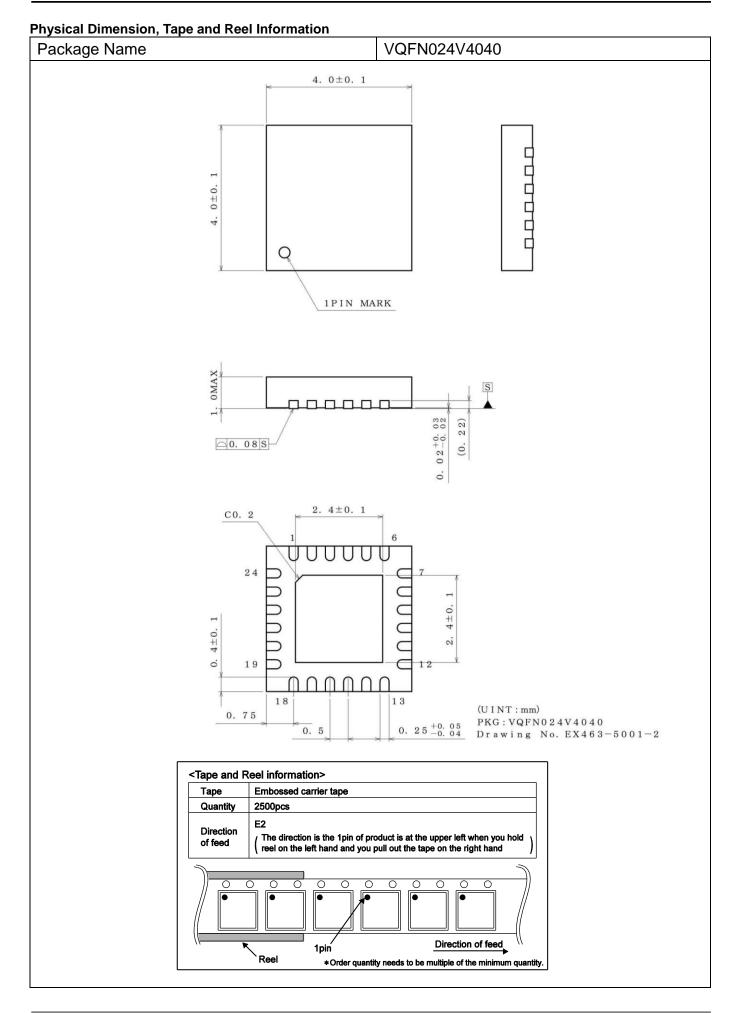
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

## **Ordering Information**



## **Marking Diagram**





## **Revision History**

ſ	Date	Revision	Changes
	19.Feb.2016	001	New Release

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(Note1) Medical Equipment Classification of the Specific Applications
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JÁPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ		CLASSⅢ	

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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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For details, please refer to ROHM Mounting specification

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